

6367254 MOTOROLA SC (XSTRS/R F)

96D 80575 D
T-33-19

**MOTOROLA
SEMICONDUCTOR
TECHNICAL DATA**

**BD234
BD236
BD238**

**PLASTIC MEDIUM POWER
SILICON PNP TRANSISTOR**

... designed for use in 5 to 10 Watt audio amplifiers and drivers utilizing complementary or quasi complementary circuits.

- DC Current Gain— $h_{FE} = 40$ (Min) @ $I_C = 0.15$ Adc
- BD 234, 236, 238 are complementary with BD 233, 235, 237

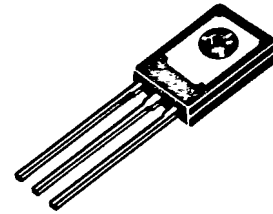
**2 AMPERE
POWER TRANSISTOR**

PNP SILICON

45, 60, 80 VOLTS
25 WATTS

MAXIMUM RATINGS

Rating	Symbol	Type	Value	Unit
Collector-Emitter Voltage	V_{CEO}	BD 234	45	Vdc
		BD 236	60	
		BD 238	80	
Collector-Base Voltage	V_{CBO}	BD 234	45	Vdc
		BD 236	60	
		BD 238	80	
Emitter-Base Voltage	V_{EBO}		5	Vdc
Collector Current	I_C		2.0	Adc
Base Current	I_B		1.0	Adc
Total Device Dissipation $T_C = 25^\circ\text{C}$	P_D		25	Watts
Operating and Storage Junction Temperature Range	T_J, T_{stg}		-55 to +150	$^\circ\text{C}$



THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	θ_{JC}	5.0	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Type	Min	Max	Unit
Collector-Emitter Sustaining Voltage* ($I_C = 0.1$ Adc, $I_B = 0$)	V_{CEO}^*	BD 234 BD 236 BD 238	45 60 80	—	Vdc
Collector Cutoff Current ($V_{CB} = 45$ Vdc, $I_E = 0$) ($V_{CB} = 60$ Vdc, $I_E = 0$) ($V_{CB} = 80$ Vdc, $I_E = 0$)	I_{CBO}	BD 234 BD 236 BD 238	—	0.1 0.1 0.1	mAdc
Emitter Cutoff Current ($V_{BE} = 5.0$ Vdc, $I_C = 0$)	I_{EBO}		—	1.0	mAdc
DC current Gain ($I_C = 0.15$ A, $V_{CE} = 2$ V) ($I_C = 1$ A, $V_{CE} = 2$ V)	h_{FE1} h_{FE2}		40	—	
Collector-Emitter Saturation Voltage* ($I_C = 1$ Adc, $I_B = 0.1$ Adc)	$V_{CE(sat)}^*$		—	0.6	Vdc
Base-Emitter On Voltage* ($I_C = 1$ Adc, $V_{CE} = 2.0$ Vdc)	$V_{BE(on)}^*$		—	1.3	Vdc
Current-Gain-Bandwidth Product ($I_C = 250$ mAdc, $V_{CE} = 10$ Vdc, $f = 1.0$ MHz)	f_T		3.0	—	MHz

* Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$.

DIM.		MILLIMETERS		INCHES	
		MIN.	MAX.	MIN.	MAX.
A	12.80	11.04	0.432	0.429	
B	7.62	7.14	0.279	0.275	
C	7.62	7.00	0.275	0.275	
D	0.51	0.25	0.010	0.010	
F	0.61	0.17	0.015	0.015	
G	0.50	0.46	0.01	0.01	
H	1.27	0.41	0.016	0.016	
J	0.50	0.43	0.015	0.015	
K	0.61	0.01	0.015	0.015	
M	0.76	—	—	—	
Q	0.25	0.21	0.008	0.008	
R	0.15	0.38	0.005	0.005	
S	0.44	0.08	0.005	0.005	
U	0.61	0.53	0.016	0.016	
V	0.50	—	0.040	—	

STYLE 1
1. EMITTER
2. COLLECTOR
3. BASE

NOTES
1. REF = MAIN TERMINAL
2. LEADS, TRAIL POSITIONED WITHIN 0.25mm (0.010") DIA TO DIM A & B AT MAXIMUM MATERIAL CONDITION.

**CASE 77-05
TO-126**



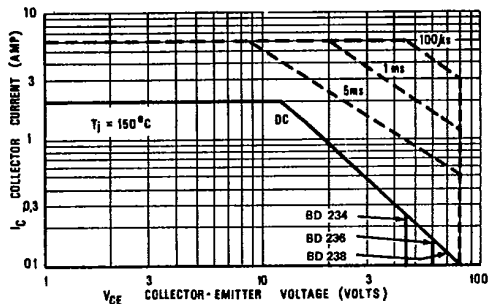
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BD234, BD236, BD238

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FIGURE 1 - ACTIVE-REGION SAFE OPERATING AREA



The Safe Operating Area Curves indicate I_C - V_{CE} limits below which the device will not enter secondary breakdown. Collector load lines for specific circuits must fall within the applicable Safe Area to avoid causing a catastrophic failure. To insure operation below the maximum T_J , power-temperature derating must be observed for both steady state and pulse power conditions.

FIGURE 2 - COLLECTOR SATURATION REGION

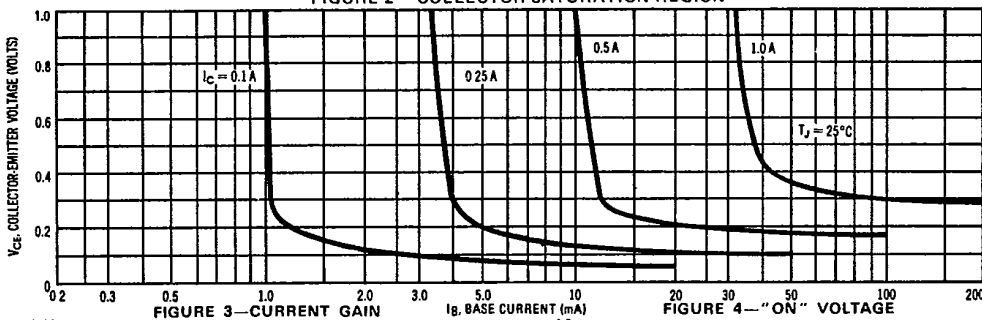


FIGURE 3 - CURRENT GAIN

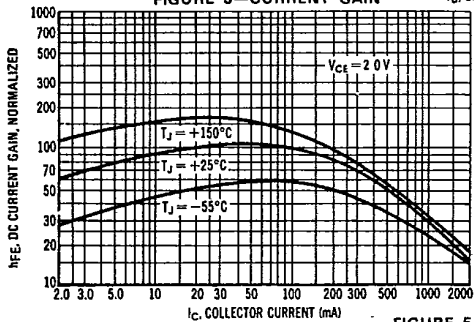


FIGURE 4 - "ON" VOLTAGE

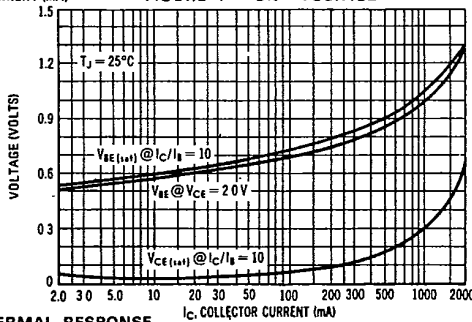


FIGURE 5 - THERMAL RESPONSE

